## NSN 5961-01-371-2625

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View Online at https://aerobasegroup.com/nsn/5961-01-371-2625 **Inclosure Material:** Metal **Overall Length:** 0.922 inches **Overall Height:** 0.185 inches **Overall Width:** Between 0.790 inches and 0.809 inches **End Application:** N/tpx-42trans/pwrsp **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case: Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 80.0 collector to base voltage/static/emitter open and 80.0 collector to emitter voltage/static/base open and 3.5 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 1.00 amperes source cutoff current **Power Rating Per Characteristic:** 21.9 watts forward power dissipation, dc preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Precious Material And Location:** Metallization gold **Test Data Document:** 98738-48+246142 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 2 ribbon and 1 case Shelf Life: N/a

No

**Unit Of Measure:** 

**Demilitarization:** 

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